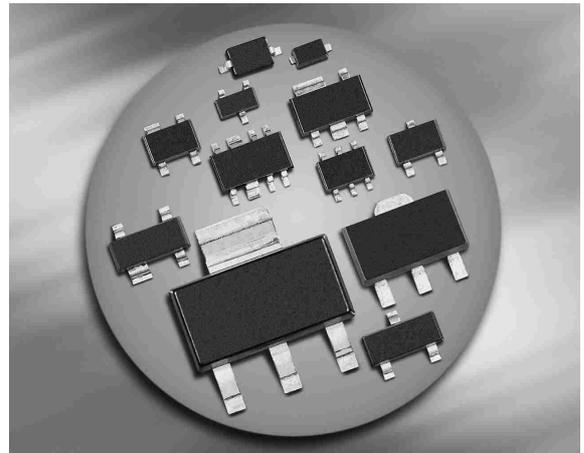
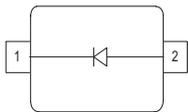


Silicon Schottky Diodes

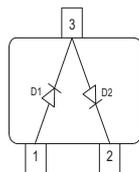
- Low barrier type for DBS mixer applications up to 12 GHz, phase detectors and modulators
- Low noise figure
- Pb-free (RoHS compliant) package



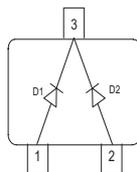
BAT15-02EL
BAT15-02ELS
BAT15-03W



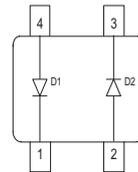
BAT15-04W



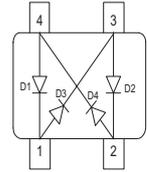
BAT15-05W



BAT15-099



BAT15-099R



ESD (Electrostatic discharge) sensitive device, observe handling precaution!

| Type | Package | Configuration | L_S (nH) | Marking |
|-------------|-----------|--------------------|------------|-------------|
| BAT15-02EL | TSLP-2-19 | single, leadless | 0.4 | NN |
| BAT15-02ELS | TSSLP-2-3 | single, leadless | 0.2 | S underline |
| BAT15-03W | SOD323 | single | 1.8 | white P |
| BAT15-04W | SOT323 | series | 1.4 | S8s |
| BAT15-05W | SOT323 | common cathode | 1.4 | S5s |
| BAT15-099 | SOT143 | anti-parallel pair | 2 | S5s |
| BAT15-099R | SOT143 | cross-over ring | 2 | S6s |

Maximum Ratings at $T_A = 25\text{ °C}$, unless otherwise specified

| Parameter | Symbol | Value | Unit |
|---|-----------|---|------|
| Diode reverse voltage | V_R | 4 | V |
| Forward current | I_F | 110 | mA |
| Total power dissipation BAT15-02ELS, $T_S \leq 73\text{ °C}$ BAT15-02EL, $T_S \leq 76\text{ °C}$ BAT15-03W, $T_S \leq 70\text{ °C}$ BAT15-04W, $T_S \leq 68\text{ °C}$ BAT15-05W, $T_S \leq 65\text{ °C}$ BAT15-099, $T_S \leq 48\text{ °C}$ BAT15-099R, $T_S \leq 67\text{ °C}$ | P_{tot} | 100 100 100 100 100 100 100 | |
| Junction temperature | T_j | 150 | °C |
| Operating temperature range | T_{op} | -55 ... 150 | |
| Storage temperature | T_{stg} | -55 ... 150 | |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
|---|------------|--|------|
| Junction - soldering point ¹⁾ BAT15-02ELS BAT15-02EL BAT15-03W BAT15-04W BAT15-05W BAT15-099 BAT15-099R | R_{thJS} | ≤ 770 ≤ 780 ≤ 795 ≤ 820 ≤ 850 ≤ 1020 ≤ 830 | |

¹⁾For calculation of R_{thJA} please refer to Application Note AN077 (Thermal Resistance Calculation)

Electrical Characteristics at $T_A = 25\text{ °C}$, unless otherwise specified

| Parameter | Symbol | Values | | | Unit |
|--|--------------|--------------|--------------|--------------|---------------|
| | | min. | typ. | max. | |
| DC Characteristics | | | | | |
| Breakdown voltage $I_{(BR)} = 100\text{ }\mu\text{A}$ | $V_{(BR)}$ | 4 | - | - | V |
| Reverse current $V_R = 1\text{ V}$ | I_R | - | - | 5 | μA |
| Forward voltage $I_F = 1\text{ mA}$ $I_F = 10\text{ mA}$ | V_F | 0.16 0.25 | 0.23 0.32 | 0.32 0.41 | V |
| Forward voltage matching ¹⁾ $I_F = 10\text{ mA}$ | ΔV_F | - | - | 20 | mV |

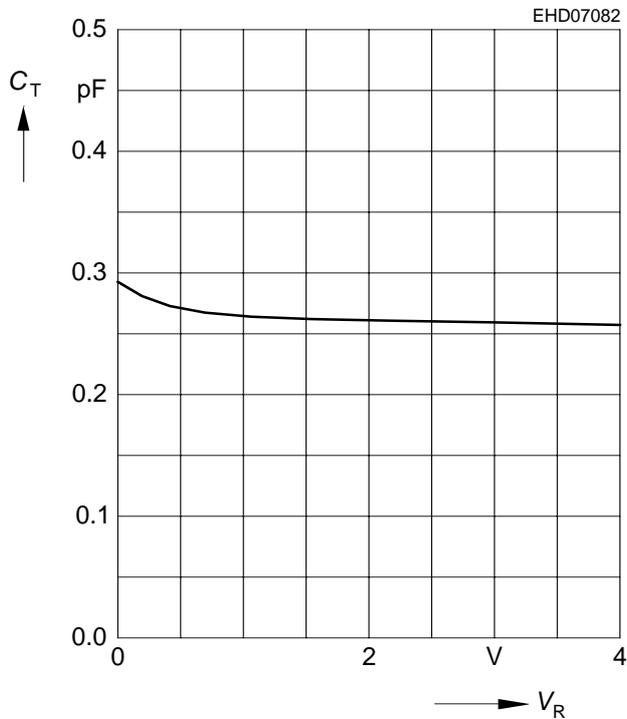
AC Characteristics

| | | | | | |
|--|-------|-------------|-------------|---------------------|----------|
| Diode capacitance $V_R = 0\text{ V}$, $f = 1\text{ MHz}$, BAT15-02ELS $V_R = 0\text{ V}$, $f = 1\text{ MHz}$, BAT15-099R $V_R = 0\text{ V}$, $f = 1\text{ MHz}$, all others types | C_T | - - - | - - - | 0.23 0.5 0.35 | pF |
| Differential forward resistance $I_F = 10\text{ mA} / 50\text{ mA}$ | R_F | - | 5.5 | - | Ω |

¹⁾ ΔV_F is the difference between lowest and highest V_F in a multiple diode component.

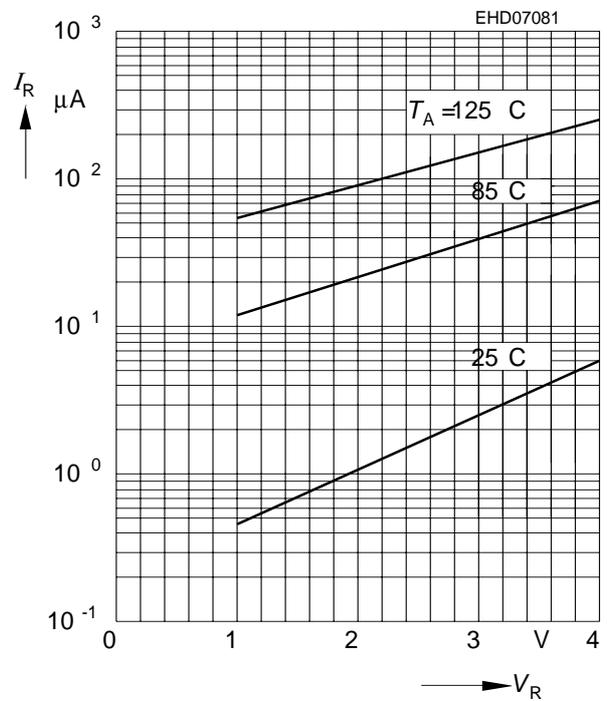
Diode capacitance $C_T = f(V_R)$

$f = 1\text{MHz}$



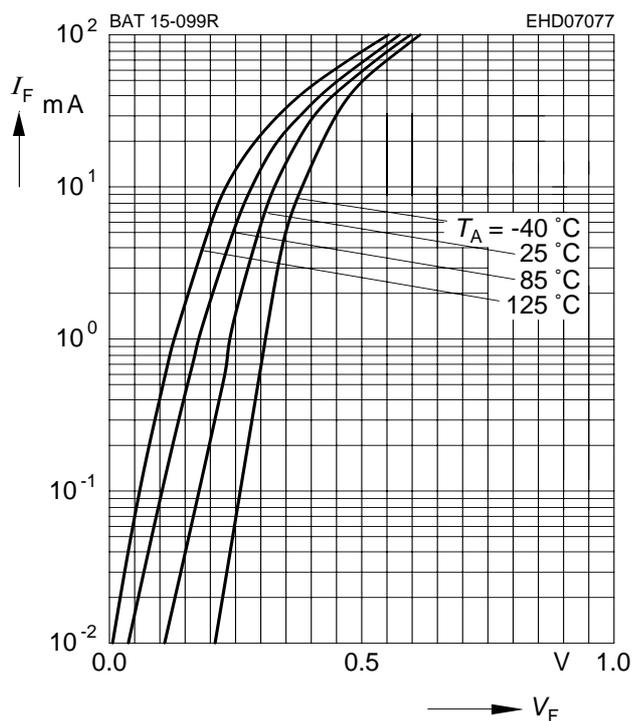
Reverse current $I_R = f(V_R)$

$T_A = \text{Parameter}$



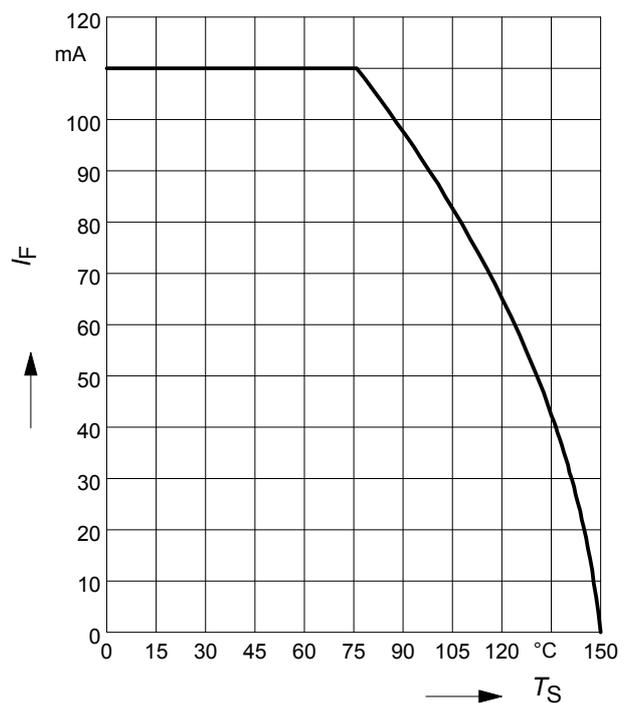
Forward current $I_F = f(V_F)$

$T_A = \text{Parameter}$



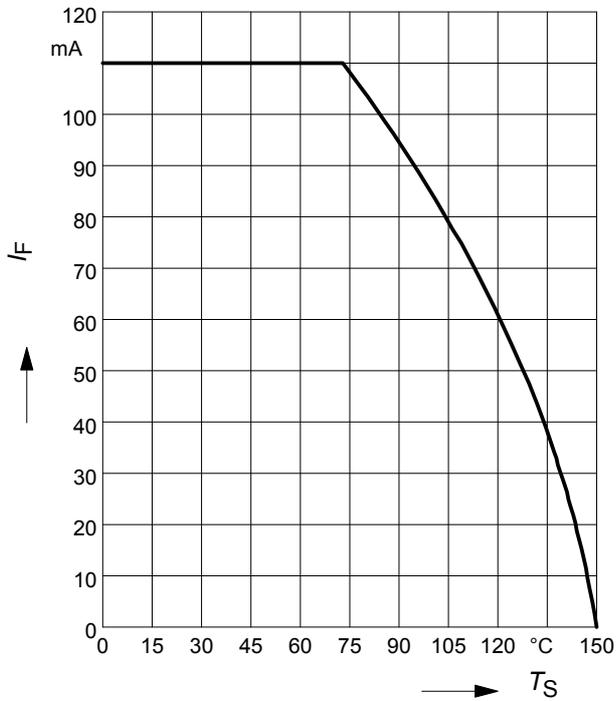
Forward current $I_F = f(T_S)$

BAT15-02EL



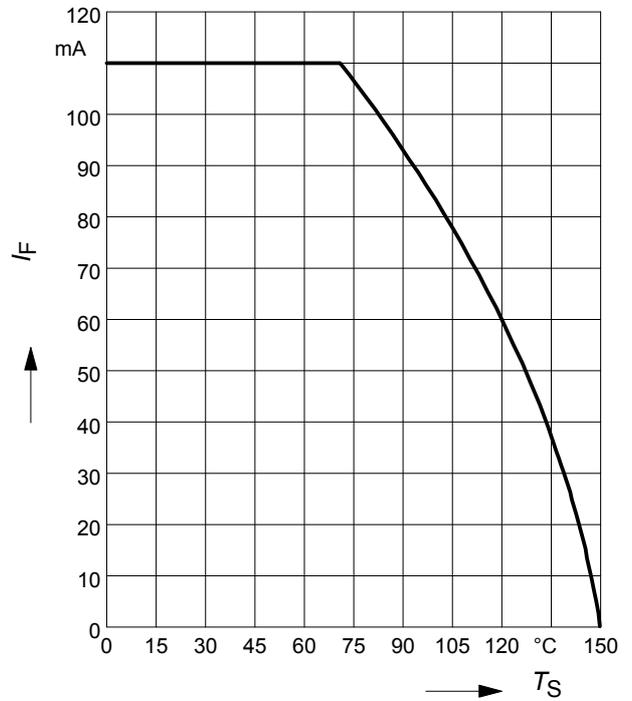
Forward current $I_F = f(T_S)$

BAT15-02ELS



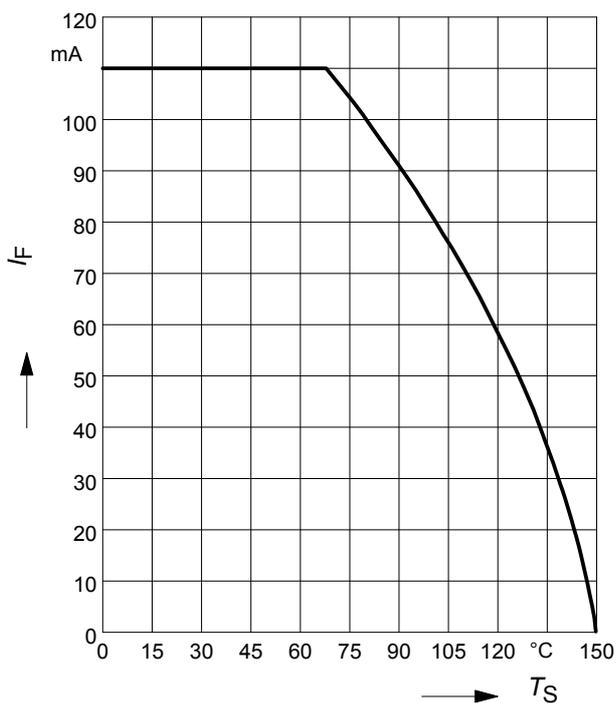
Forward current $I_F = f(T_S)$

BAT15-03W



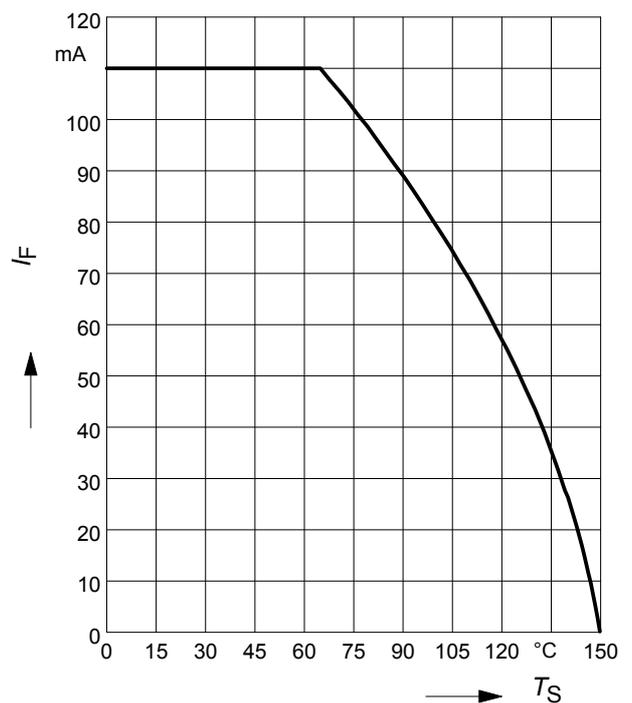
Forward current $I_F = f(T_S)$

BAT15-04W



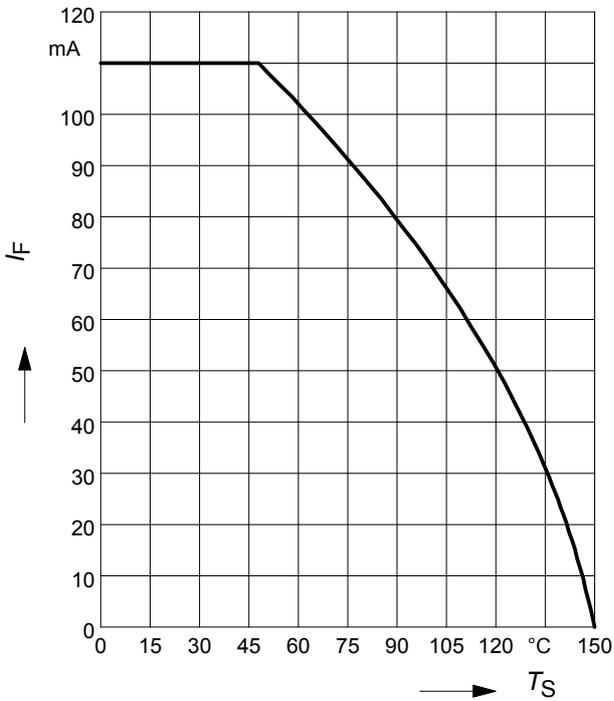
Forward current $I_F = f(T_S)$

BAT15-05W



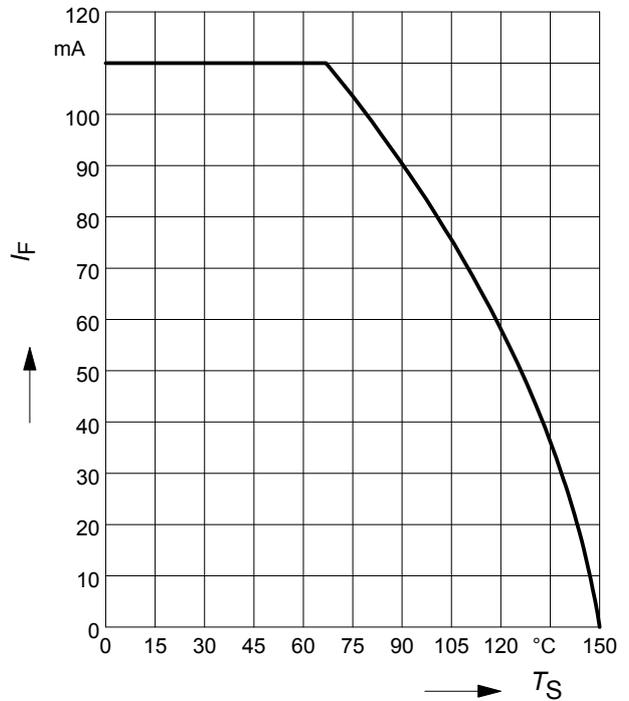
Forward current $I_F = f(T_S)$

BAT15-099



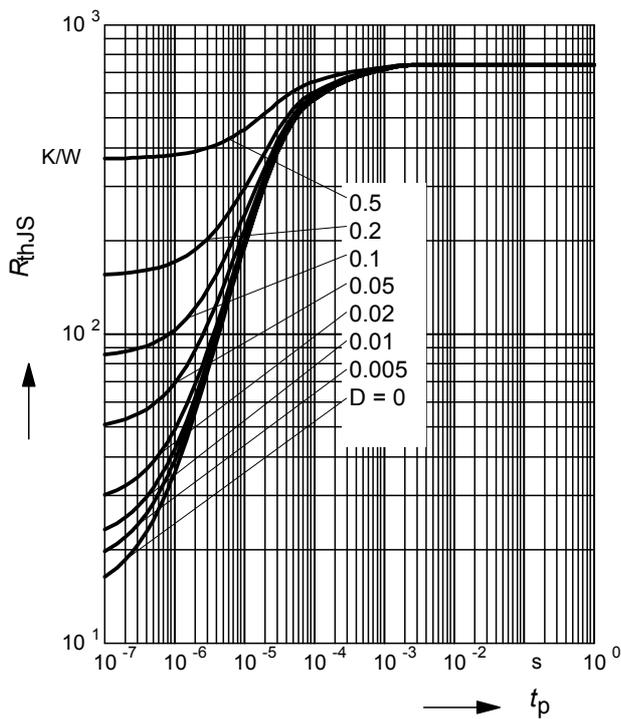
Forward current $I_F = f(T_S)$

BAT15-099R



Permissible Puls Load $R_{thJS} = f(t_p)$

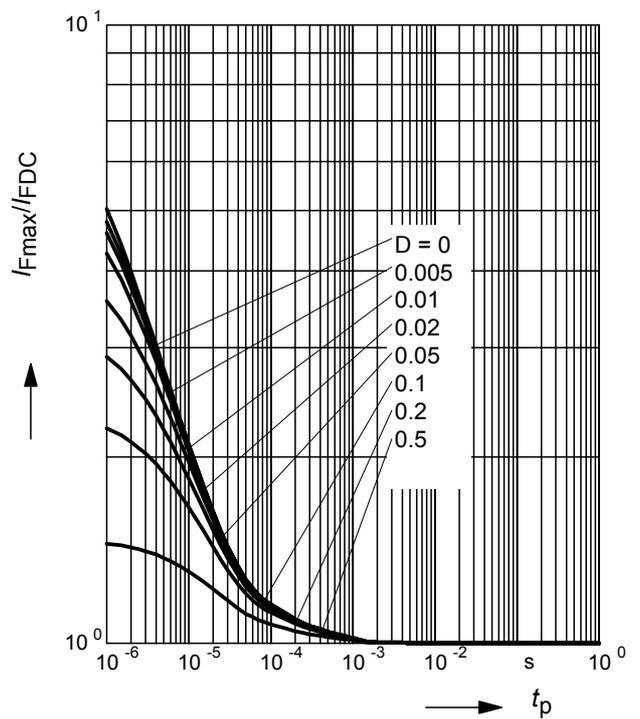
BAT15-02EL



Permissible Pulse Load

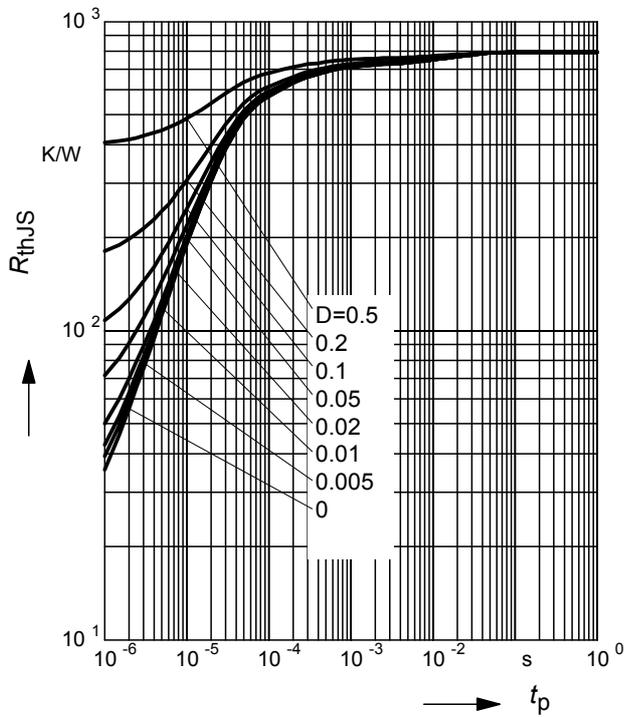
$I_{Fmax} / I_{FDC} = f(t_p)$

BAT15-02EL



Permissible Puls Load $R_{thJS} = f(t_p)$

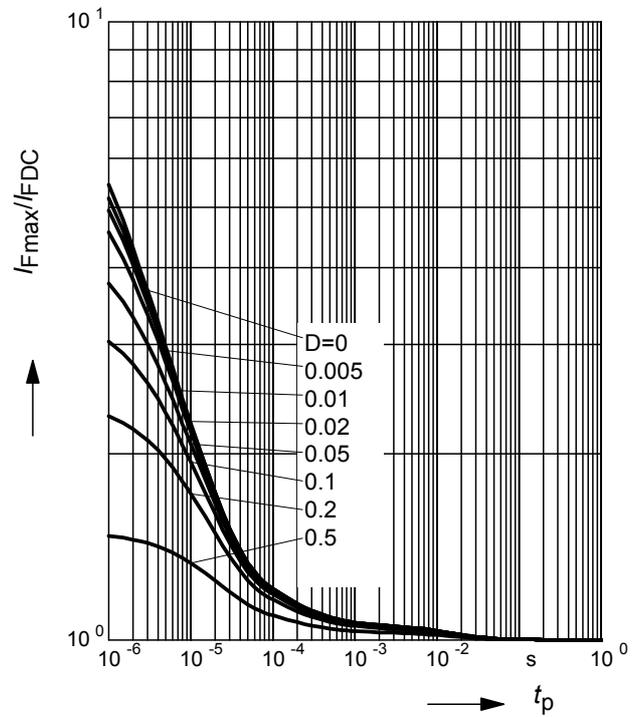
BAT15-03W



Permissible Pulse Load

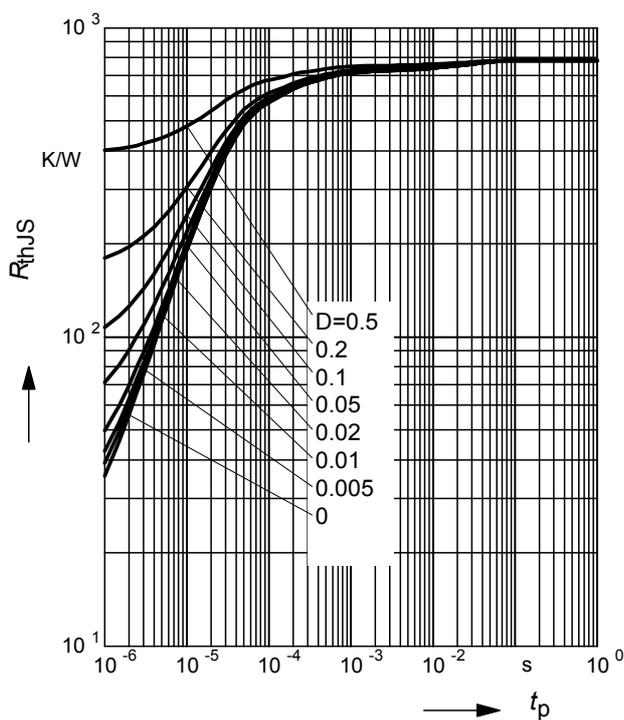
$I_{Fmax} / I_{FDC} = f(t_p)$

BAT15-03W



Permissible Puls Load $R_{thJS} = f(t_p)$

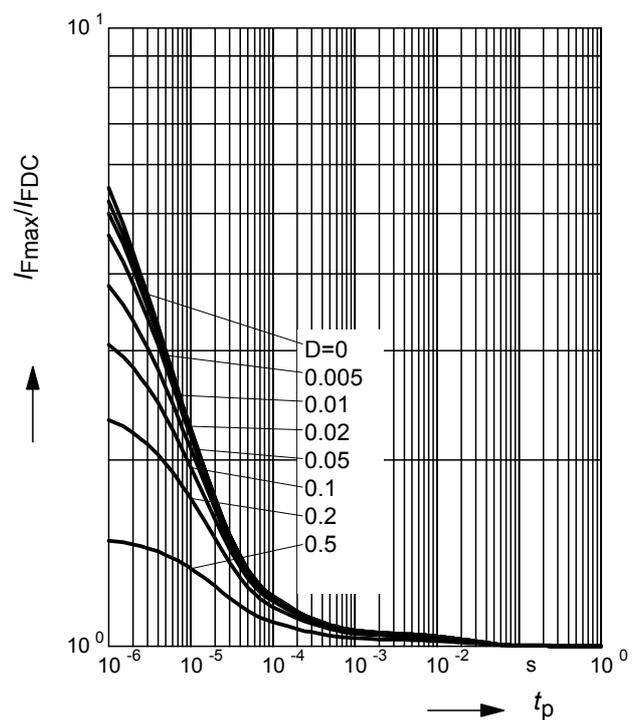
BAT15-04W



Permissible Pulse Load

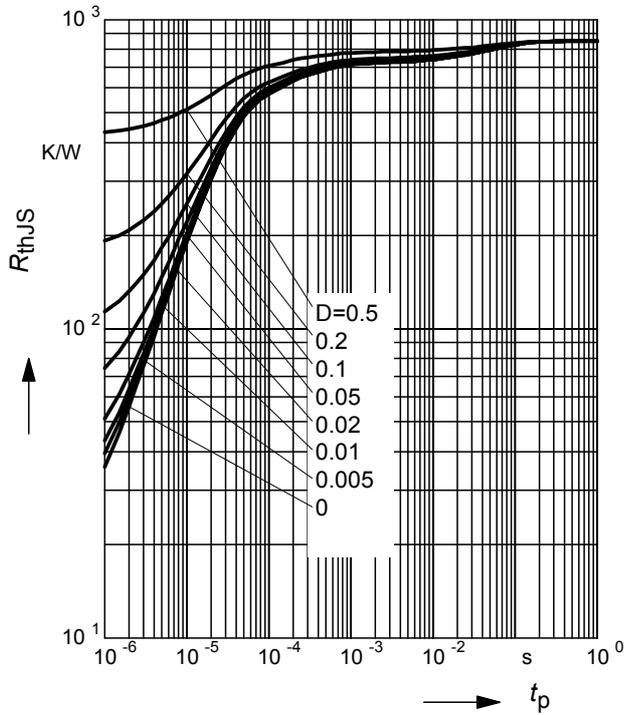
$I_{Fmax} / I_{FDC} = f(t_p)$

BAT15-04W



Permissible Puls Load $R_{thJS} = f(t_p)$

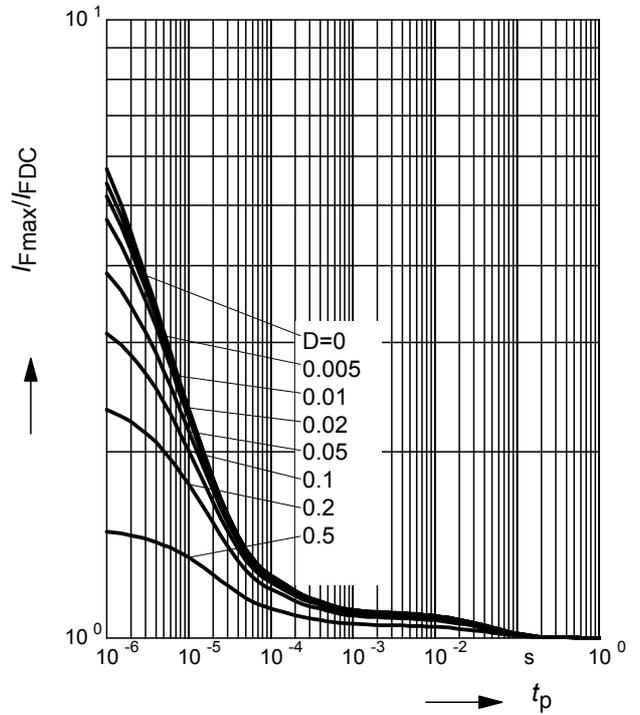
BAT15-05W



Permissible Pulse Load

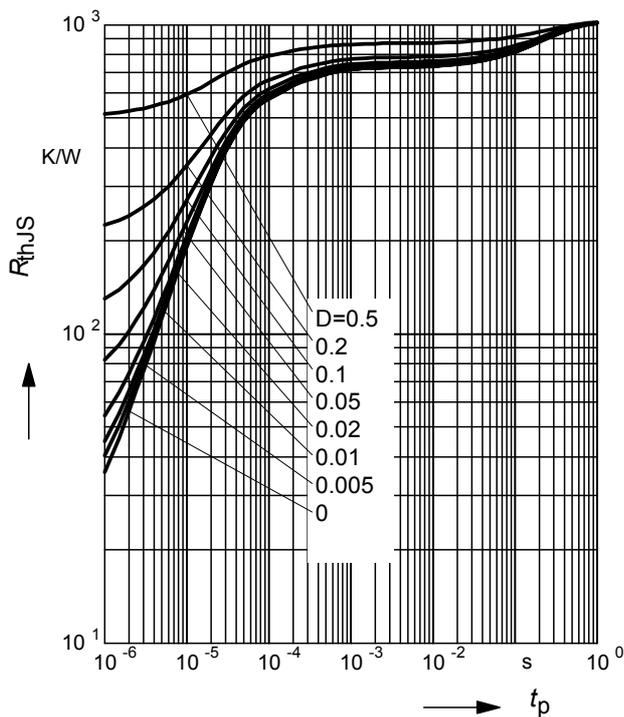
$I_{Fmax} / I_{FDC} = f(t_p)$

BAT15-05W



Permissible Puls Load $R_{thJS} = f(t_p)$

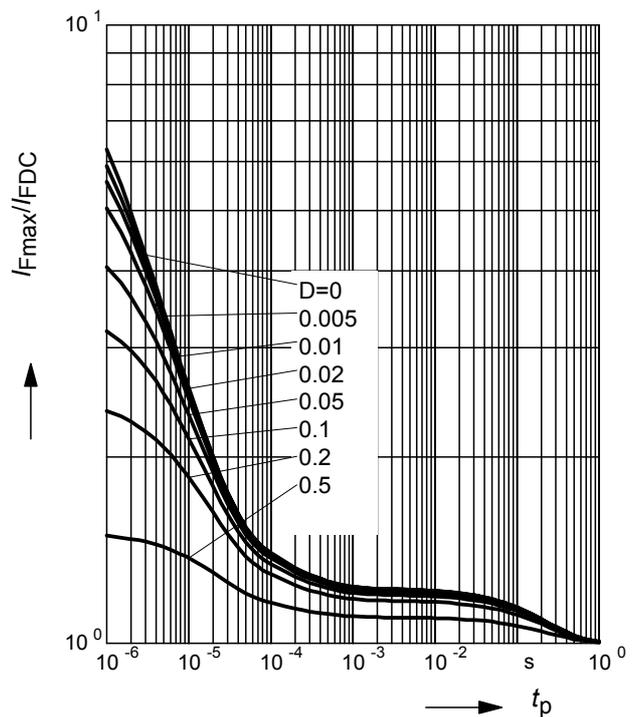
BAT15-099



Permissible Pulse Load

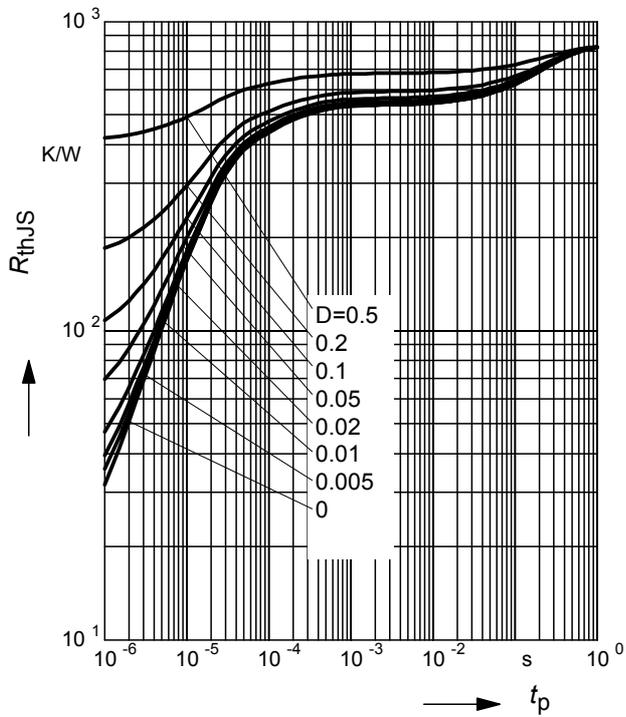
$I_{Fmax} / I_{FDC} = f(t_p)$

BAT15-099



Permissible Puls Load $R_{thJS} = f(t_p)$

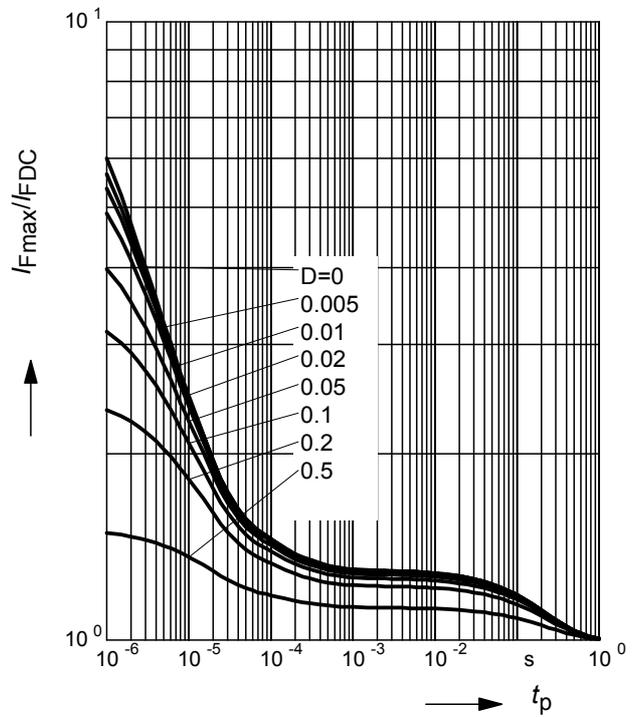
BAT15-099R



Permissible Pulse Load

$I_{Fmax} / I_{FDC} = f(t_p)$

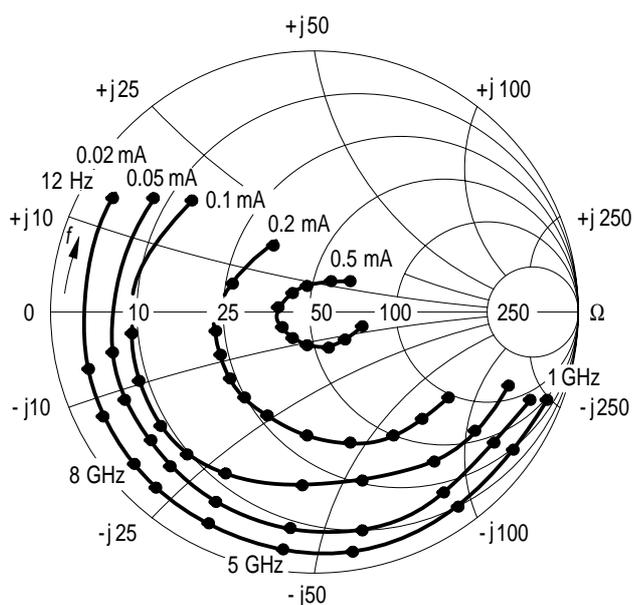
BAT15-099R



S₁₁-Parameters for BAT15-099

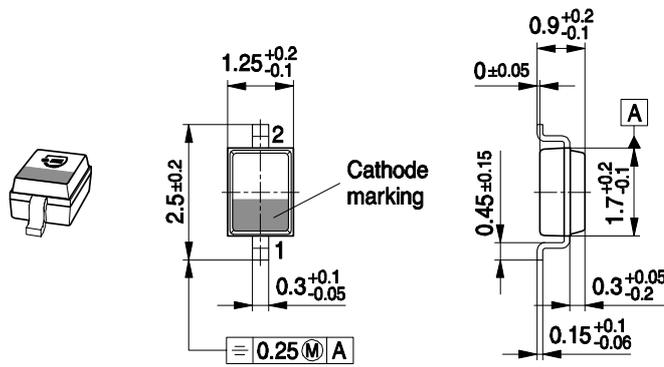
 Typical impedance characteristics (with external bias I and $Z_0 = 50\Omega$)

| f | $I = 0.02 \text{ mA}$ | | $I = 0.05 \text{ mA}$ | | $I = 0.1 \text{ mA}$ | | $I = 0.2 \text{ mA}$ | | $I = 0.5 \text{ mA}$ | |
|-----|-----------------------|--------|-----------------------|--------|----------------------|--------|----------------------|--------|----------------------|--------|
| GHz | MAG | ANG | MAG | ANG | MAG | ANG | MAG | ANG | MAG | ANG |
| 1 | 0.94 | -16.4 | 0.84 | -16.6 | 0.77 | -16.4 | 0.59 | -17.2 | 0.19 | -16.7 |
| 2 | 0.93 | -33.8 | 0.88 | -33.8 | 0.77 | -34.5 | 0.58 | -35.2 | 0.15 | -36.1 |
| 3 | 0.92 | -53.8 | 0.86 | -54.5 | 0.75 | -54.1 | 0.58 | -56.1 | 0.13 | -64.8 |
| 4 | 0.91 | -74.3 | 0.84 | -75.3 | 0.72 | -76.4 | 0.51 | -78.4 | 0.11 | -104.8 |
| 5 | 0.91 | -96.6 | 0.84 | -97.6 | 0.72 | -99.1 | 0.53 | -102.3 | 0.15 | -135.7 |
| 6 | 0.91 | -115.4 | 0.84 | -116.7 | 0.73 | -118.7 | 0.53 | -122.9 | 0.18 | -160.9 |
| 7 | 0.91 | -131 | 0.84 | -132.3 | 0.73 | -134.1 | 0.54 | -138.1 | 0.2 | -168.8 |
| 8 | 0.91 | -143 | 0.84 | -144.5 | 0.73 | -146.8 | 0.55 | -150.5 | 0.81 | 179.4 |
| 9 | 0.91 | -155.6 | 0.83 | -150.2 | 0.71 | -159.7 | 0.53 | -163.9 | 0.18 | 179.4 |
| 10 | 0.9 | -167.3 | 0.83 | -169.7 | 0.71 | -178.8 | 0.51 | -175.8 | 0.14 | 151.2 |
| 11 | 0.89 | 175.5 | 0.8 | 172.6 | 0.7 | 170 | 0.45 | 164.9 | 0.09 | 105.5 |
| 12 | 0.88 | 175.5 | 0.76 | 146.5 | 0.62 | 142.8 | 0.39 | 134.2 | 0.14 | 43.6 |

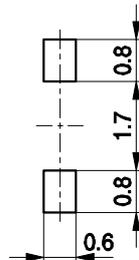
S₁₁ = (f, I) BAT15-099


EHD07083

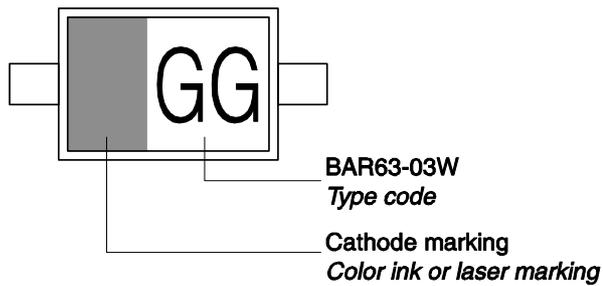
Package Outline



Foot Print

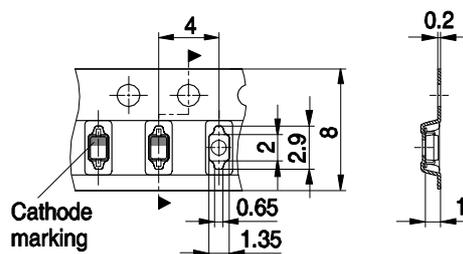


Marking Layout (Example)

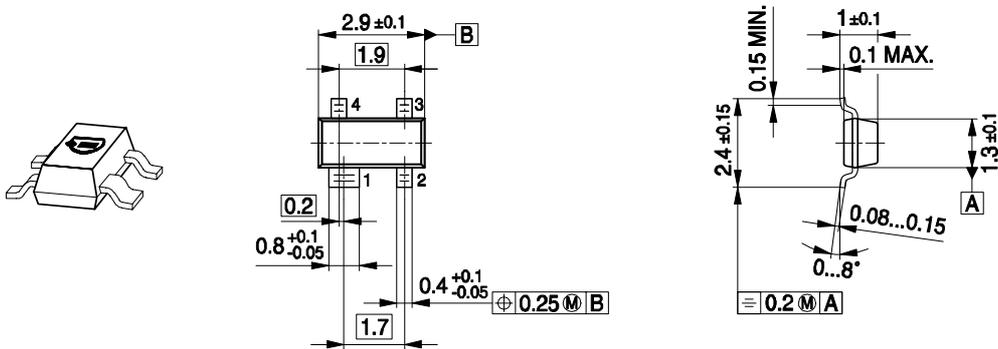


Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
 Reel ø330 mm = 10.000 Pieces/Reel



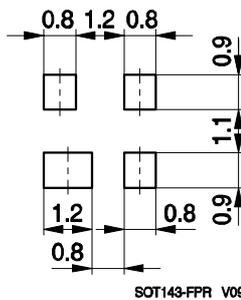
Package Outline



Note: Mold flash, protrusions or gate burrs of 0,2 mm max. per side are not included

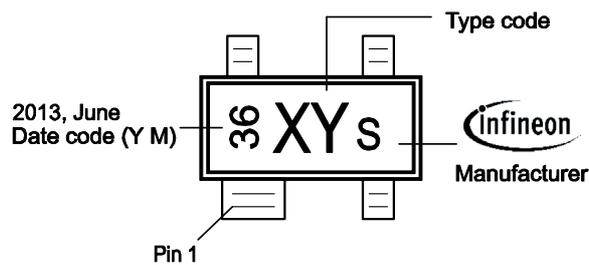
SOT143-PO V09

Foot Print



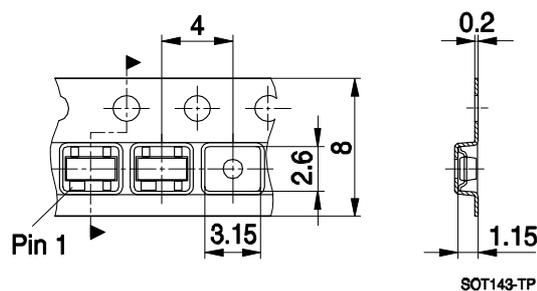
SOT143-FPR V09

Marking Layout (Example)



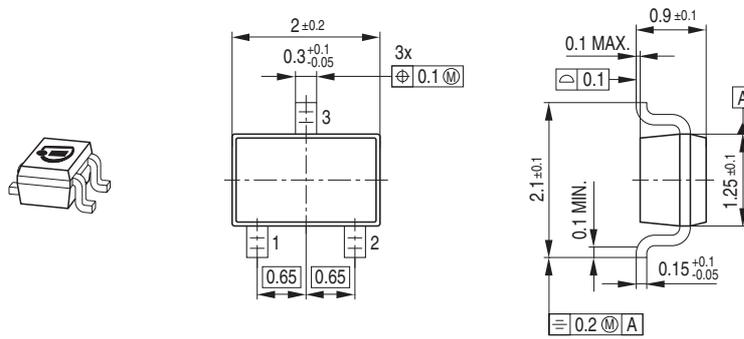
Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
 Reel ø330 mm = 10.000 Pieces/Reel

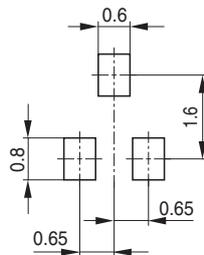


SOT143-TP

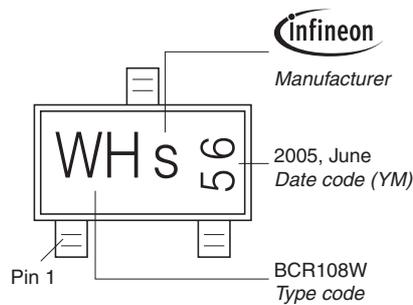
Package Outline



Foot Print

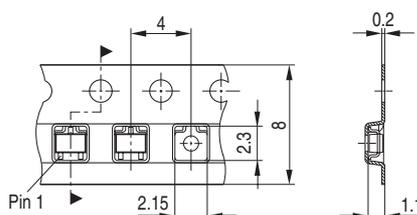


Marking Layout (Example)

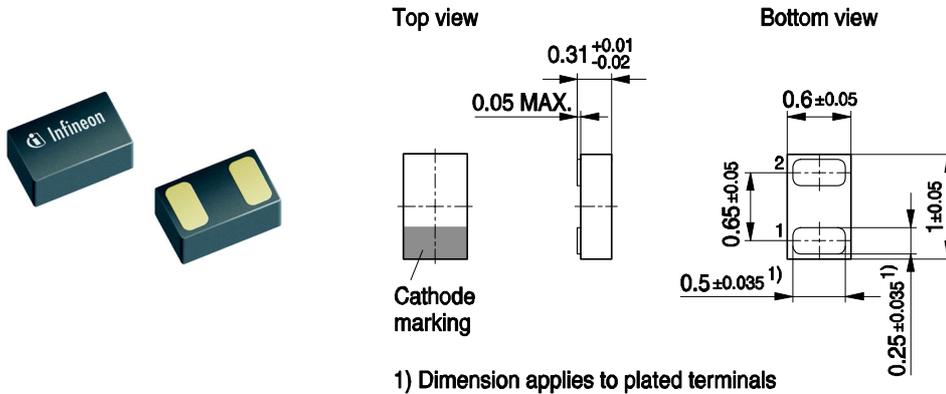


Standard Packing

Reel \varnothing 180 mm = 3.000 Pieces/Reel
 Reel \varnothing 330 mm = 10.000 Pieces/Reel



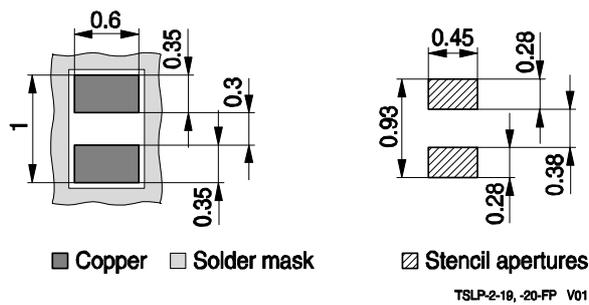
Package Outline



TSLP-2-19, -20-PO V01

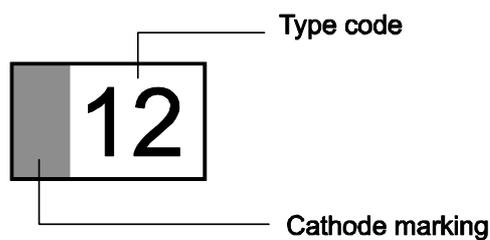
Foot Print

For board assembly information please refer to Infineon website „Packages“



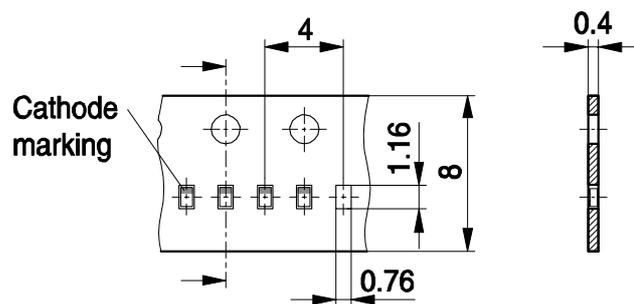
TSLP-2-19, -20-FP V01

Marking layout (Example)



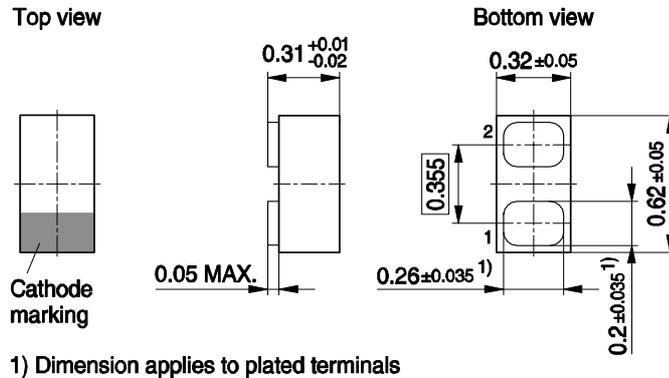
Standard Packing

Reel Ø 180 mm: 15.000 Pieces / Reel
Reels/Box: 1



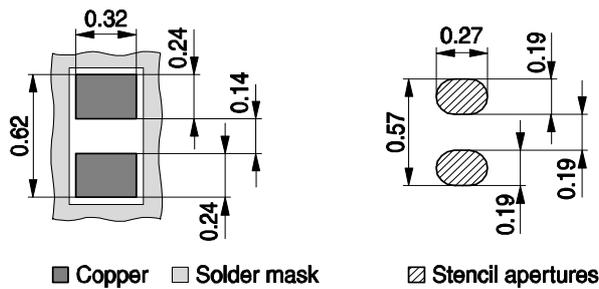
TSLP-2-19, -20-TP V02

Package Outline

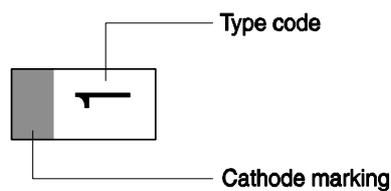


Foot Print

For board assembly information please refer to Infineon website "Packages"

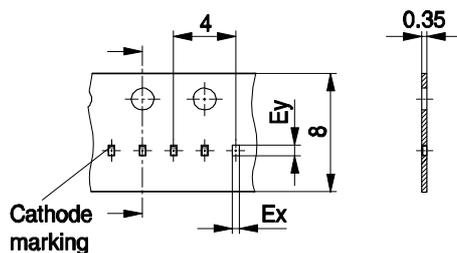


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel



| Tape type | Ex | Ey |
|---------------|------|------|
| Punched Tape | 0.43 | 0.73 |
| Embossed Tape | 0.37 | 0.67 |

Deliveries can be both tape types (no selection possible). Specification allows identical processing (pick & place) by users.

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